

FEATURES

- Low Forward Voltage Drop
- Guard Ring Construction For Transient Protection
- Negligible Reverse Recovery Time
- Low Capacitance

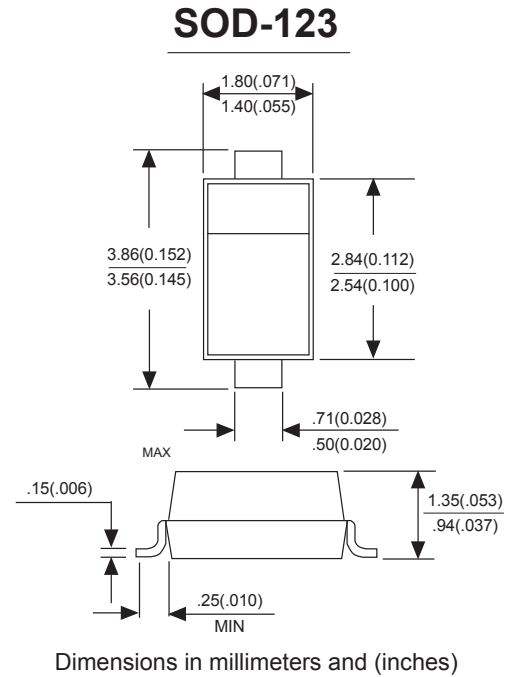
MECHANICAL DATA

Case: Molded plastic body

Terminals: Plated leads solderable per MIL-STD-750, Method 2026

Polarity: Polarity symbols marked on case

Marking: S4



MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)

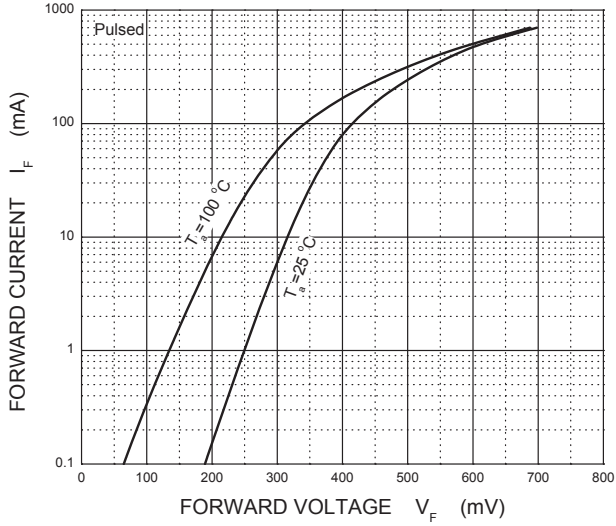
Symbol	Parameter	Value	Unit
		SD10AW	
V_{RRM}	Peak Repetitive Reverse Voltage	40	V
V_{RWM}	Working Peak Reverse Voltage		
$V_{R(RMS)}$	RMS Reverse Voltage	28	V
I_{FM}	Forward Continuous Current	350	mA
I_{FSM}	Non-repetitive Peak Forward Surge Current@t= 8.3ms	2	A
P_D	Power Dissipation	400	mW
$R_{\theta JA}$	Thermal Resistance from Junction to Ambient	250	$^\circ\text{C}/\text{W}$
T_j	Junction Temperature	125	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55 ~ +150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS($T_a=25^\circ\text{C}$ unless otherwise specified)

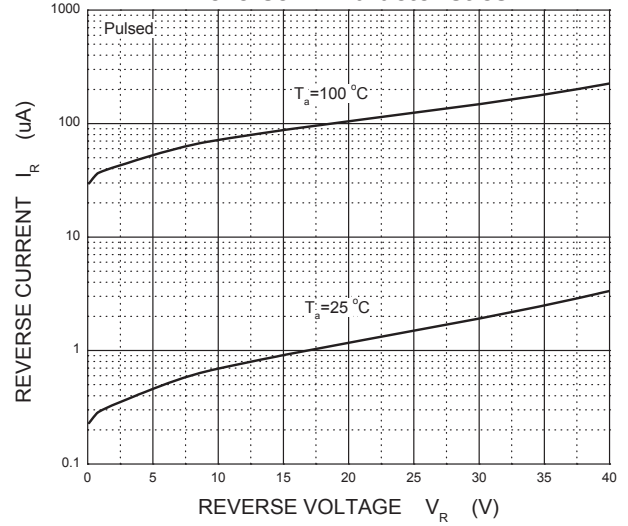
Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse voltage	$V_{(BR)}$	$I_R=100 \mu\text{A}$	40			V
Reverse current	I_R				5	μA
Forward voltage	V_F	$I_F=20\text{mA}$			0.37	V
		$I_F=200\text{mA}$			0.6	
Total capacitance	C_{tot}	$V_R=0\text{V}$, $f=1\text{MHz}$		50		pF
Reverse recovery time	t_{rr}	$I_F=I_R=200\text{mA}$, $I_{rr}=0.1 \times I_R$, $R_L=100 \Omega$		10		ns



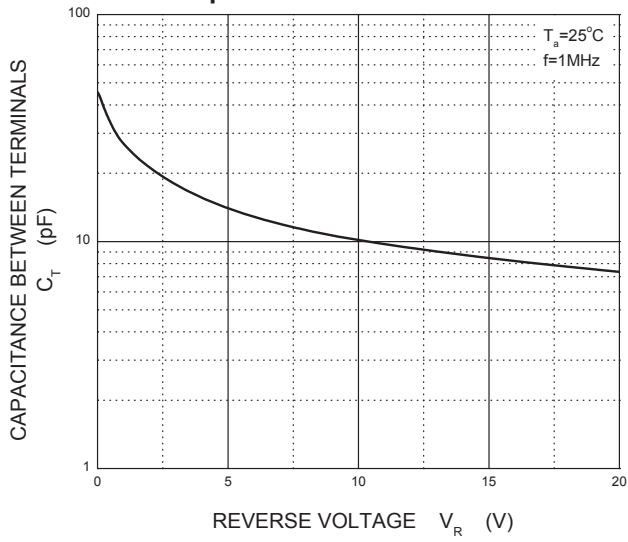
Forward Characteristics



Reverse Characteristics



Capacitance Characteristics



Power Derating Curve

